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**Answer any Five Questions One Question from One UNIT**  
**ALL the Questions Carry Equal Marks**  
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<b>UNIT-I</b>		<b>Marks</b>	<b>CO</b>	<b>BL</b>
1.a)	Explain static and dynamic characteristics of an n-channel enhancement MOSFET with neat diagrams.	6M	CO1	BL5
b)	Describe the steps involved in converting a stick diagram to a full layout diagram for a CMOS inverter.	6M	CO1	BL3
<b>OR</b>				
2.a)	Explain how transistor sizing affects the switching threshold and noise margins of a CMOS inverter.	6M	CO1	BL5
b)	Draw the stick diagram of a CMOS inverter and explain the representation of NMOS, PMOS, and interconnections.	6M	CO1	BL5
<b>UNIT-II</b>		<b>Marks</b>	<b>CO</b>	<b>BL</b>
3.a)	Describe the use of logical effort in sizing gates for minimum delay in a multi-stage logic path.	6M	CO2	BL3
b)	Discuss the problems in dynamic logic and suggest remedies.	6M	CO2	BL2
<b>OR</b>				
4.a)	Explain dynamic properties of CMOS gates and the factors affecting them.	6M	CO2	BL5
b)	Explain the techniques used to reduce interconnect delay.	6M	CO2	BL5
<b>UNIT-III</b>		<b>Marks</b>	<b>CO</b>	<b>BL</b>
5.a)	Explain the principle of operation of a dynamic register implemented using dynamic latches.	6M	CO3	BL5
b)	What is pipelining in digital circuits? Explain how pipelining improves throughput with a suitable example.	6M	CO3	BL5
<b>OR</b>				
6.a)	What are non-bistable sequential circuits? Give examples and explain their principle of operation.	6M	CO3	BL5
b)	Discuss timing issues in sequential circuits.	6M	CO3	BL2
<b>UNIT-IV</b>		<b>Marks</b>	<b>CO</b>	<b>BL</b>
7.a)	Explain the operation of a ripple-carry adder. Discuss its advantages and limitations.	6M	CO4	BL5
b)	Describe the design of an accumulator that supports load, clear, and accumulate operations.	6M	CO4	BL3

**OR**

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|------|---|----|-----|-----|
| 8.a) | What is a barrel shifter? Draw and explain the architecture of a barrel shifter using multiplexers.                               | 6M | CO4 | BL5 |
| b)   | What is a data path in a digital system? Explain the main components of a typical arithmetic data path with a neat block diagram. | 6M | CO4 | BL5 |

**UNIT-V**

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|------|---|--------------|-----------|-----------|
| 9.a) | Distinguish between static RAM (SRAM) and dynamic RAM (DRAM)                | 6M           | CO5       | BL2       |
| b)   | Explain memory architectures used in VLSI systems with neat block diagrams. | 6M           | CO5       | BL5       |

**OR**

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|-------|--|----|-----|-----|
| 10.a) | Draw the circuit diagram of a 6-transistor (6T) CMOS SRAM cell and explain its operation during READ and WRITE cycles. | 8M | CO5 | BL5 |
| b)    | Define the function of a sense amplifier in memory.  | 4M | CO5 | BL1 |

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